



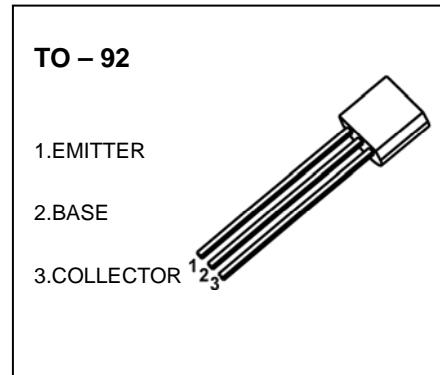
DONGGUAN NANJING ELECTRONICS LTD.,

## TO-92 Plastic-Encapsulate Transistors

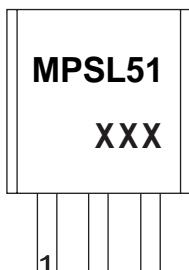
### MPSL51 TRANSISTOR (PNP)

#### FEATURES

- General Purpose Amplifier

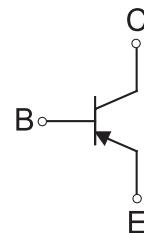


#### MARKING



MPSL51=Device code  
XXX=Code

#### Equivalent Circuit



#### ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
MPSL51	TO-92	Bulk	1000pcs/Bag
MPSL51-TA	TO-92	Tape	2000pcs/Box

#### MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	-100	V
$V_{CEO}$	Collector-Emitter Voltage	-100	V
$V_{EBO}$	Emitter-Base Voltage	-4	V
$I_C$	Collector Current	200	mA
$P_C$	Collector Power Dissipation	625	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	200	°C/W
$T_J, T_{stg}$	Operation Junction and Storage Temperature Range	-55~+150	°C

## ELECTRICAL CHARACTERISTICS

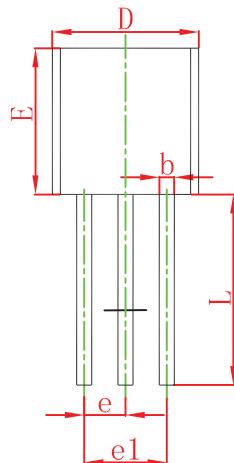
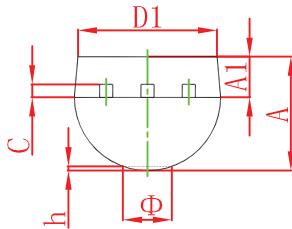
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$T_a=25^\circ\text{C}$  unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
<b>Collector-base breakdown voltage</b>	$V_{(\text{BR})\text{CBO}}$	$I_C=-0.1\text{mA}, I_E=0$	-100			V
<b>Collector-emitter breakdown voltage</b>	$V_{(\text{BR})\text{CEO}}^*$	$I_C=-1\text{mA}, I_B=0$	-100			V
<b>Emitter-base breakdown voltage</b>	$V_{(\text{BR})\text{EBO}}$	$I_E=-0.01\text{mA}, I_C=0$	-4			V
<b>Collector cut-off current</b>	$I_{\text{CBO}}$	$V_{\text{CB}}=-50\text{V}, I_E=0$			-1	$\mu\text{A}$
<b>Emitter cut-off current</b>	$I_{\text{EBO}}$	$V_{\text{EB}}=-3\text{V}, I_C=0$			-0.1	$\mu\text{A}$
<b>DC current gain</b>	$h_{\text{FE}}^*$	$V_{\text{CE}}=-5\text{V}, I_C=-50\text{mA}$	40		250	
<b>Collector-emitter saturation voltage</b>	$V_{\text{CE}(\text{sat})(1)}^*$	$I_C=-10\text{mA}, I_B=-1\text{mA}$			-0.25	V
	$V_{\text{CE}(\text{sat})(2)}^*$	$I_C=-50\text{mA}, I_B=-5\text{mA}$			-0.3	V
<b>Base-emitter saturation voltage</b>	$V_{\text{BE}(\text{sat})(1)}^*$	$I_C=-10\text{mA}, I_B=-1\text{mA}$			-1.2	V
	$V_{\text{BE}(\text{sat})(2)}^*$	$I_C=-50\text{mA}, I_B=-5\text{mA}$			-1.2	V
<b>Transition frequency</b>	$f_T$	$V_{\text{CE}}=10\text{V}, I_C=10\text{mA}, f=20\text{MHz}$	60			MHz
<b>Collector output capacitance</b>	$C_{\text{ob}}$	$V_{\text{CB}}=10\text{V}, I_E=0, f=1\text{MHz}$			8	pF

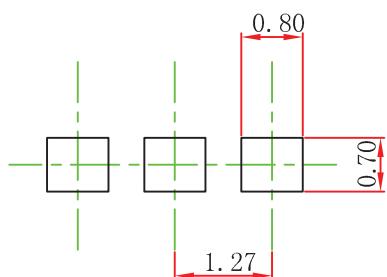
\*Pulse test: pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2.0\%$ .

## TO-92 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

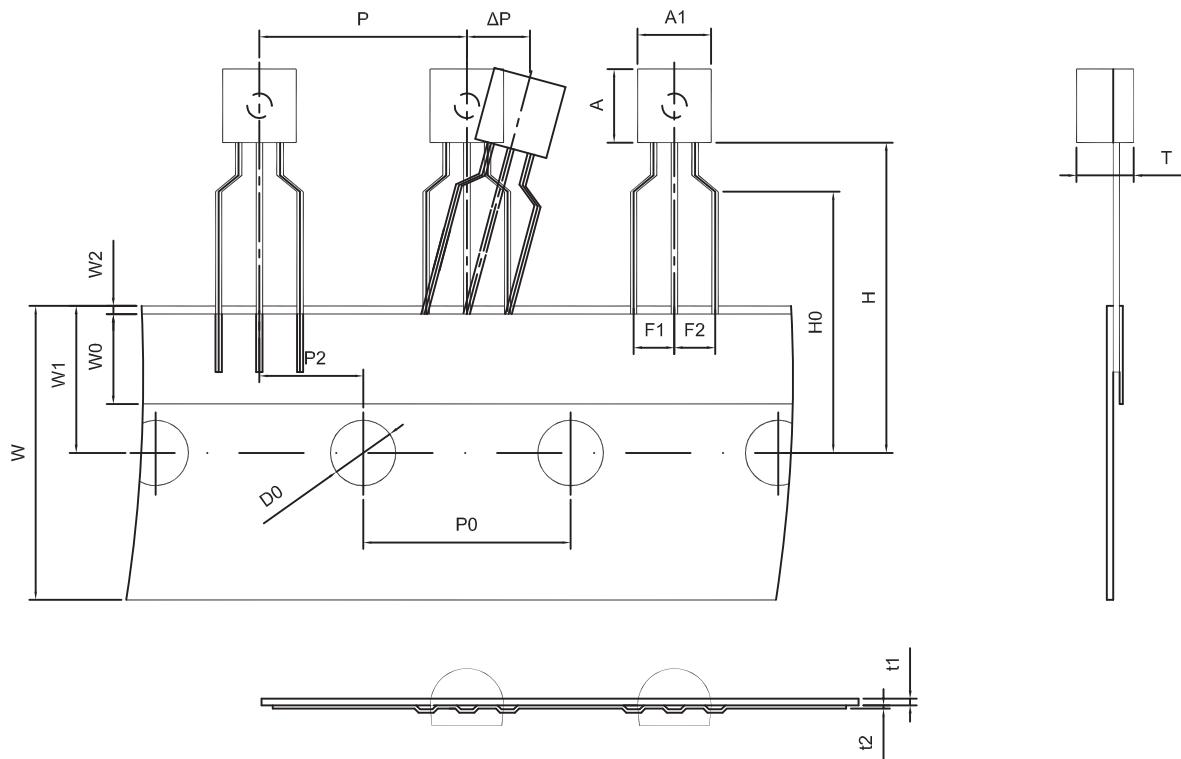
## TO-92 Suggested Pad Layout



### Note:

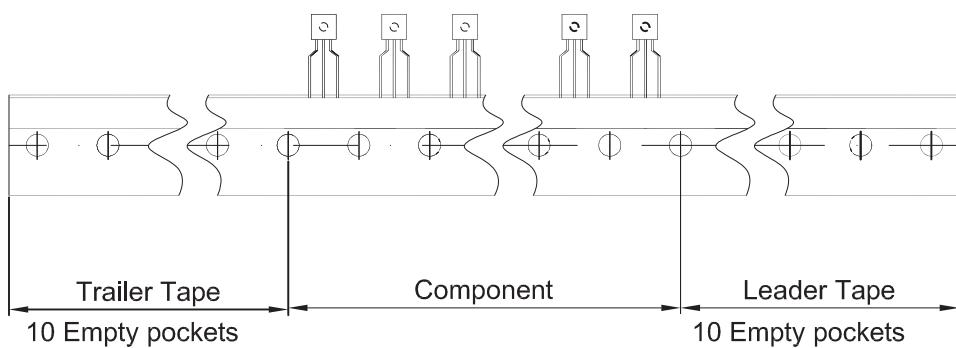
1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

## TO-92 Tape and Reel



Dimensions are in millimeter

A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250